

150 mA 10 V Input LDO Regulator for Industrial Applications

No. EA-342-200219

OUTLINE

The RP171x is a LDO regulator featuring 150 mA output current. The RP171x offers the maximum input voltage of 10 V which makes it ideal for use in the industrial equipments such as FAs and smart meters. The RP171x provides a supply current as low as Typ. 23 μ A and achieves fast-response characteristics. The RP171x offers an output voltage as low as 1.2 V. Compared to existing high-speed lines, the RP171x provides excellent output voltage accuracy and output voltage temperature coefficient.

Internally, the RP171x consists of a fold-back protection circuit and a thermal shutdown circuit. A standby mode with ultra low supply current has been realized by a chip enable function.

The RP171x is available in a 5-pin SOT-23-5 package with high power dissipation.

This is a high-reliability semiconductor device for industrial application (-Y) that has passed both the screening at high temperature and the reliability test with extended hours.

FEATURES

- Input Voltage Range (Maximum Ratings) 2.6 V to 10 V (12 V)
- Operating Temperature -40°C to 105°C
- Supply Current Typ. 23 μ A ($V_{IN} = V_{SET} + 1.0$ V)
- Standby Current Typ. 0.1 μ A ($V_{IN} = 10.0$ V, CE = "L")
- Output Voltage Range 1.2 V/1.5 V/1.8 V/2.5 V/2.8 V/3.0 V/3.3 V/3.4 V
/5.0 V/6.0 V

Contact our sales representatives for other voltages.

- Output Voltage Accuracy $\pm 1.0\%$
- Output Voltage Temperature Coefficient Typ. ± 80 ppm/°C
- Line Regulation Typ. 0.02%/V
- Dropout Voltage Typ. 0.4 V ($I_{OUT} = 150$ mA, $V_{SET} = 2.8$ V)
- Ripple Rejection Typ. 70 dB ($f = 1$ kHz)
- Fold-back Protection Circuit Typ. 40 mA
- Constant Slope Circuit (Soft-start Function)
- Thermal Shutdown Circuit Stops at 165°C
- Auto-discharge Function RP171xxxxD
- Package SOT-23-5
- Ceramic Capacitor Compatible 1.0 μ F or more

APPLICATIONS

- Industrial equipments such as FAs and smart meters
- Equipments used under high-temperature conditions such as surveillance camera and vending machine
- Equipments accompanied by self-heating such as motor and lighting

SELECTION GUIDE

The set output voltage, the auto-discharge function ⁽¹⁾ and the automotive class are user-selectable options.

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
RP171Nxx1*-TR-YE	SOT-23-5	3,000 pcs	Yes	Yes

xx: Specify the set output voltage (V_{SET}) within the range of

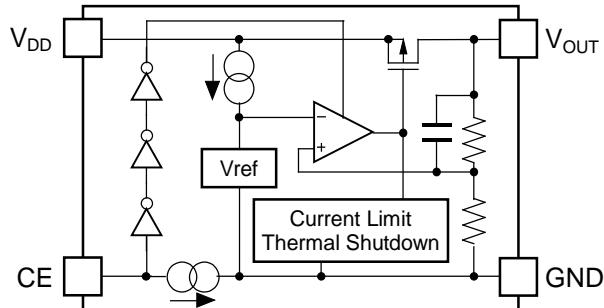
1.2 V (12) / 1.5 V (15) / 1.8 V (18) / 2.5 V (25) / 2.8 V (28) / 3.0 V (30) / 3.3 V (33) / 3.4 V (34) /
5.0 V (50) / 6.0 V (60)

Contact our sales representatives for other voltages.

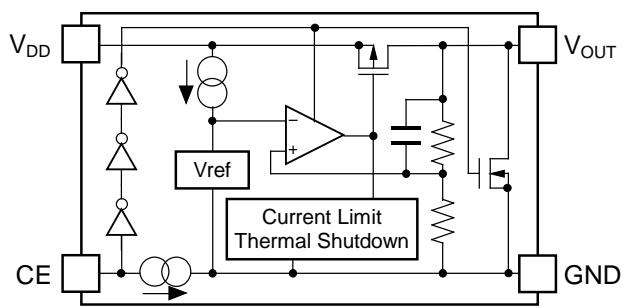
*: Select from (B) CE = Active-high without auto-discharge function or (D) CE = Active-high with Auto-discharge function.

⁽¹⁾Auto-discharge function quickly lowers the output voltage to 0 V by releasing the electrical charge accumulated in the external capacitor when the chip enable signal is switched from the active mode to the standby mode.

BLOCK DIAGRAM

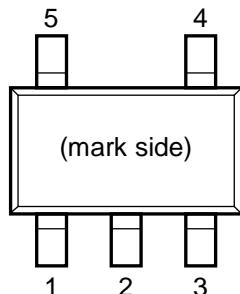


RP171xxxxB Block Diagram



RP171xxxxD Block Diagram

PIN DESCRIPTION



SOT-23 Pin Configuration

SOT-23-5

Pin No.	Symbol	Description
1	VDD	Input Pin
2	GND	Ground Pin
3	CE	Chip Enable Pin, Active-high
4	NC	No Connection
5	VOUT	Output Pin

ABSOLUTE MAXIMUM RATINGS

Symbol	Item	Rating	Unit
V _{IN}	Input Voltage	12	V
V _{CE}	Input Voltage (CE Pin)	12	V
V _{OUT}	Output Voltage	-0.3 to V _{IN} + 0.3	V
I _{OUT}	Output Current	330	mA
P _D	Power Dissipation ⁽¹⁾ (SOT-23-5 , JEDEC STD. 51-7)	660	mW
T _j	Junction Temperature	-40 to 125	°C
T _{stg}	Storage Temperature Range	-55 to 125	°C

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause permanent damage and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

RECOMMENDED OPERATING CONDITIONS

Symbol	Item	Rating	Unit
V _{IN}	Input Voltage	2.6 to 10	V
T _a	Operating Temperature Range	-40 to 105	°C

RECOMMENDED OPERATING CONDITIONS

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

⁽¹⁾ Please refer to *Power Dissipation* for detailed information.

ELECTRICAL CHARACTERISTICS

$V_{IN} = V_{SET} + 1.0 \text{ V}$, $I_{OUT} = 1 \text{ mA}$, unless otherwise noted.

The specifications surrounded by are guaranteed by design engineering at $-40^\circ\text{C} \leq Ta \leq 105^\circ\text{C}$.

RP171xxxxB/D $(Ta = 25^\circ\text{C})$						
Symbol	Item	Conditions		Min.	Typ.	Max.
V_{OUT}	Output Voltage	1.5 V < V_{SET}	$Ta = 25^\circ\text{C}$	$V_{SET} \times 0.99$		$V_{SET} \times 1.01$
			$-40^\circ\text{C} \leq Ta \leq 105^\circ\text{C}$	$V_{SET} \times 0.965$		$V_{SET} \times 1.03$
		$V_{SET} \leq 1.5 \text{ V}$	$Ta = 25^\circ\text{C}$	-15		15
			$-40^\circ\text{C} \leq Ta \leq 105^\circ\text{C}$	-53		45
I_{OUT}	Output Current			150		
$\Delta V_{OUT} / \Delta I_{OUT}$	Load Regulation	$0.1 \text{ mA} \leq I_{OUT} \leq 150 \text{ mA}$			5	45
V_{DIF}	Dropout Voltage	$I_{OUT} = 150 \text{ mA}$		Refer to the <i>Product-specific Electrical Characteristics</i>		
I_{SS}	Supply Current	$I_{OUT} = 0 \text{ mA}$		23	45	μA
I_{standby}	Standby Current	$V_{IN} = 10.0 \text{ V}$, $V_{CE} = \text{GND}$		0.1	1.2	μA
$\Delta V_{OUT} / \Delta V_{IN}$	Line Regulation	$V_{SET} + 0.5 \text{ V} \leq V_{IN} \leq 10.0 \text{ V}$ Note: When $V_{OUT} \leq 2.1 \text{ V}$, $2.6 \text{ V} \leq V_{IN} \leq 10.0 \text{ V}$		± 0.02	± 0.25	%/V
I_{SC}	Short Current Limit	$V_{OUT} = 0 \text{ V}$		40		mA
I_{PD}	CE Pull-down Current			0.30		μA
V_{CEH}	CE Input Voltage "H"			1.7		V
V_{CEL}	CE Input Voltage "L"				0.8	V
T_{TSD}	Thermal Shutdown Temperature	Junction Temperature		165		$^\circ\text{C}$
T_{TSR}	Thermal Shutdown Released Temperature	Junction Temperature		110		$^\circ\text{C}$
R_{LOW}	Auto-discharge Nch Tr. ON Resistance (RP171xxxxD)	$V_{CE} = 0 \text{ V}$, $V_{IN} = 7.0 \text{ V}$		250		Ω

All test items listed under *ELECTRICAL CHARACTERISTICS* are done under the pulse load condition ($T_j \approx Ta = 25^\circ\text{C}$).

RP171N-Y

No. EA-342-200219

Product-specific Electrical Characteristics

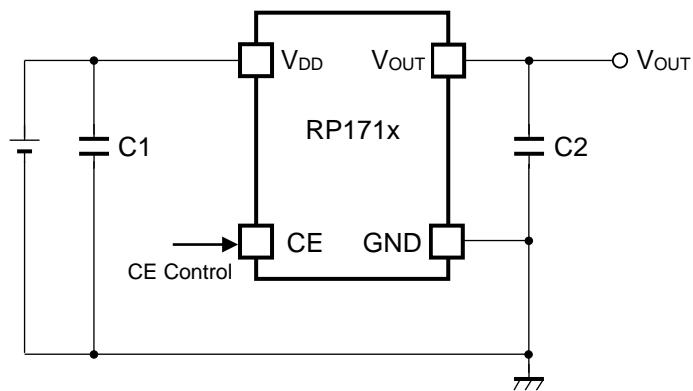
The specifications surrounded by are guaranteed by design engineering at $-40^{\circ}\text{C} \leq \text{Ta} \leq 105^{\circ}\text{C}$.

RP171xxxxB/D $(\text{Ta} = 25^{\circ}\text{C})$

Product Name	V_{OUT} (V) ($\text{Ta} = 25^{\circ}\text{C}$)			V_{OUT} (V) ($-40^{\circ}\text{C} \leq \text{Ta} \leq 105^{\circ}\text{C}$)			V_{DIF} (V) ($I_{\text{OUT}} = 150 \text{ mA}$)	
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	TYP.	MAX.
RP171x121x	1.185	1.200	1.215	1.147	1.200	1.245	-	1.405
RP171x151x	1.485	1.500	1.515	1.447	1.500	1.545	-	1.105
RP171x181x	1.782	1.800	1.818	1.737	1.800	1.854	-	0.805
RP171x251x	2.475	2.500	2.525	2.413	2.500	2.575	0.400	0.600
RP171x281x	2.772	2.800	2.828	2.702	2.800	2.884		
RP171x301x	2.970	3.000	3.030	2.895	3.000	3.090	0.300	0.500
RP171x331x	3.267	3.300	3.333	3.185	3.300	3.399		
RP171x341x	3.366	3.400	3.434	3.281	3.400	3.502	0.250	0.420
RP171x501x	4.950	5.000	5.050	4.825	5.000	5.150		
RP171x601x	5.940	6.000	6.060	5.790	6.000	6.180		

APPLICATION INFORMATION

TYPICAL APPLICATION



RP171x Typical Application

External Components

Symbol	Description
C2 (C _{OUT})	1.0 μ F, Ceramic Capacitor, MURATA GRM155B31A105KE15

RP171N-Y

No. EA-342-200219

EQUIVALENT SERIES RESISTANCE (ESR) vs. OUTPUT CURRENT (I_{OUT})

Ceramic type output capacitor is recommended for the RP171x; however, the other output capacitors with low ESR also can be used. The relations between I_{OUT} (Output Current) and ESR of an output capacitor are shown below. The conditions when the white noise level is under 40 μ V (Avg.) are marked as the hatched area in the graph.

Measurement Conditions

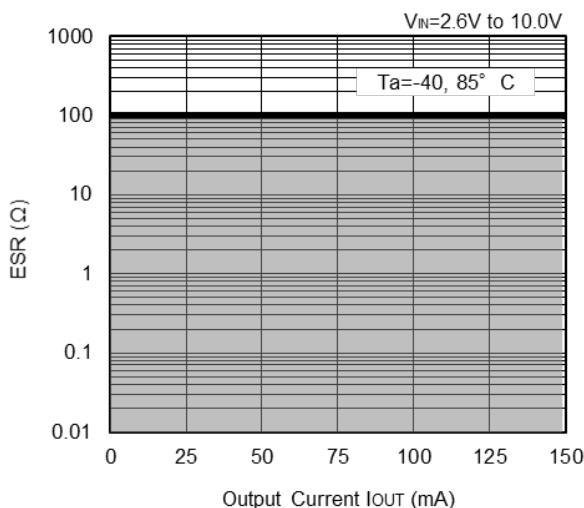
Noise Frequency Band: 10 Hz to 2 MHz

Measurement Temperature: -40°C to 85°C

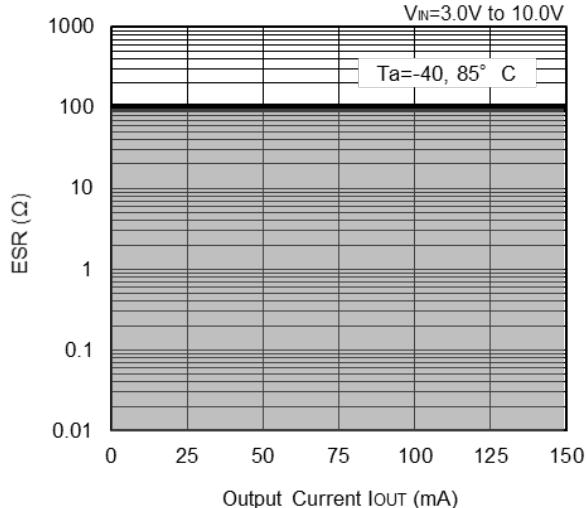
Hatched area: Noise level below 40 μ V (Avg.).

C1, C2: Ceramic 1.0 μ F (Murata, GRM155B31A105KE)

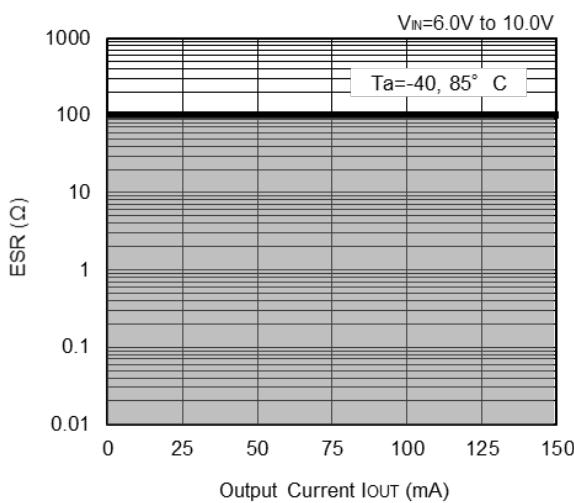
RP171x12xx



RP171x30xx



RP171x60xx



TECHNICAL NOTES

Phase Compensation

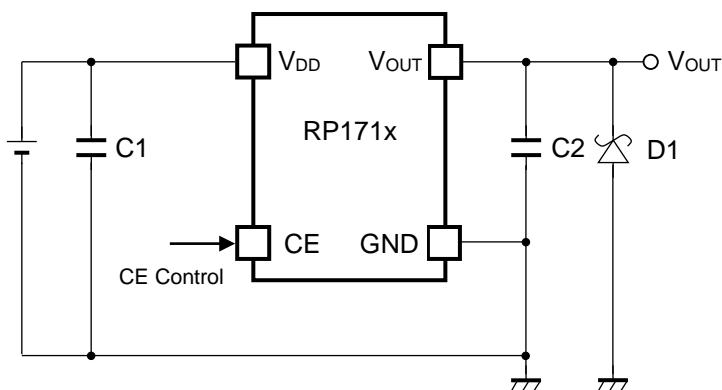
In this device, phase compensation is provided to secure stable operation even when the load current is varied. For this purpose, use a 1.0 μF or more output capacitor (C2) with good frequency characteristics and proper ESR (Equivalent Series Resistance).

In case of using a tantalum type capacitor and the ESR value of the capacitor is large, the output might be unstable. Evaluate the circuit including consideration of frequency characteristics.

PCB Layout

Ensure the V_{DD} and GND lines are sufficiently robust. If their impedance is too high, noise pickup or unstable operation may result. Connect a 1.0 μF or more output capacitor (C1) with suitable values between the V_{DD} and GND pins, and as close as possible to the pins.

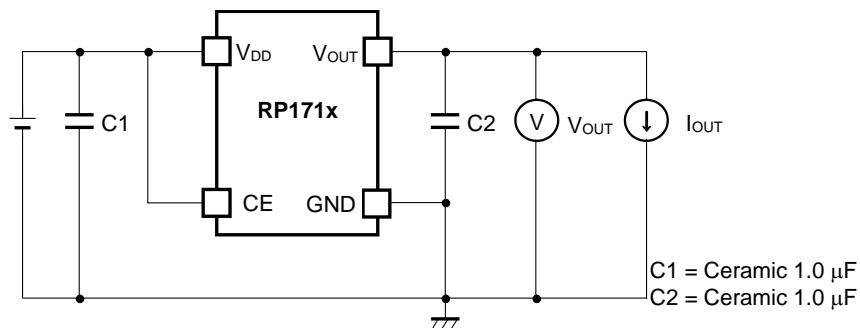
TYPICAL APPLICATION FOR IC CHIP BREAKDOWN PREVENTION



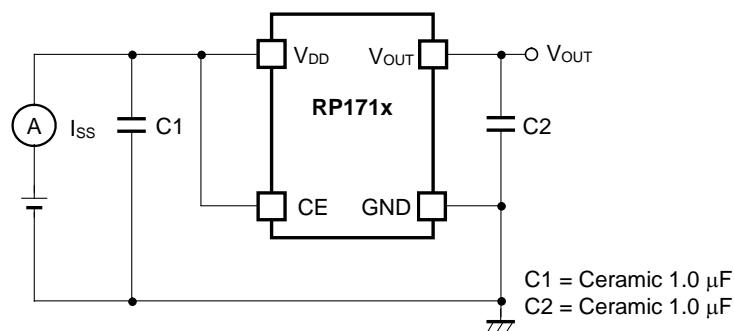
RP171x Typical Application for IC Chip Breakdown Prevention

When a sudden surge of electrical current travels along the V_{OUT} pin and GND due to a short-circuit, electrical resonance of a circuit involving an output capacitor (C2) and a short circuit inductor generates a negative voltage and may damage the device or the load devices. Connecting a schottky diode (D1) between the V_{OUT} pin and GND has the effect of preventing damage to them.

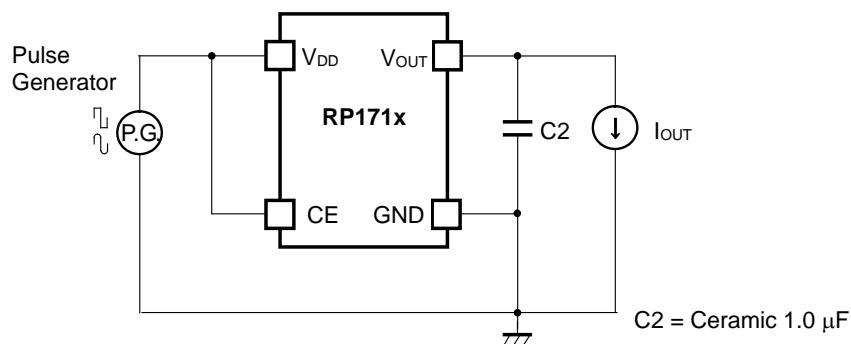
TEST CIRCUITS



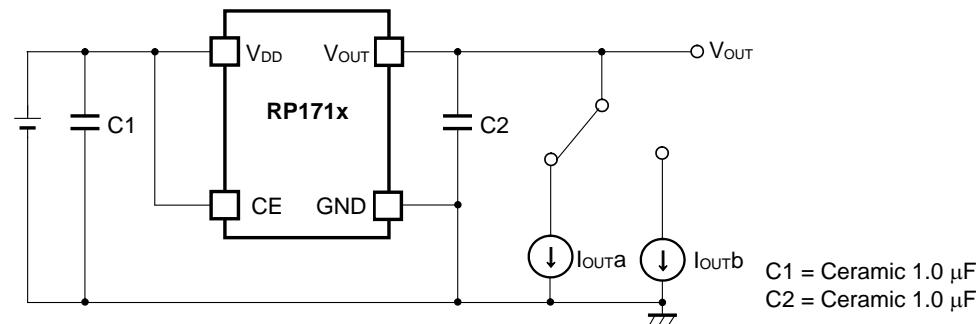
Basic Test Circuit



Test Circuit for Supply Current



Test Circuit for Ripple Rejection

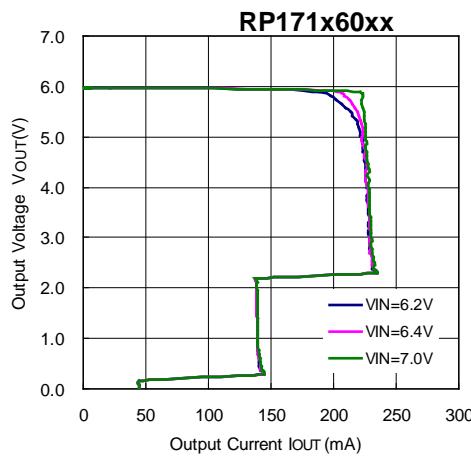
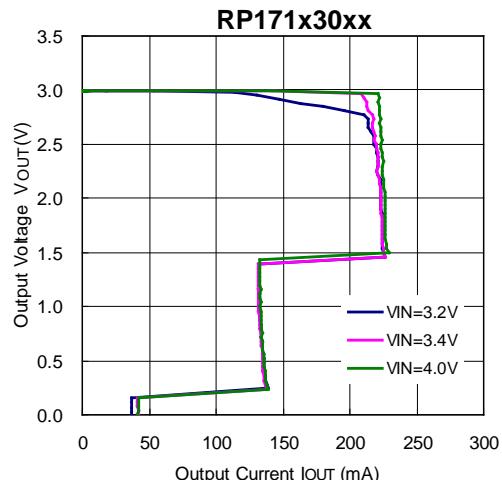
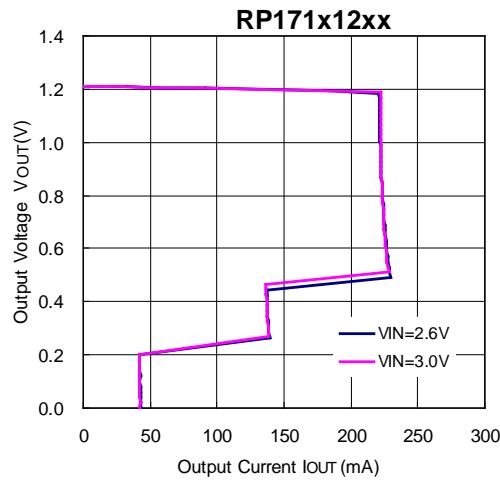


Test Circuit for Load Transient Response

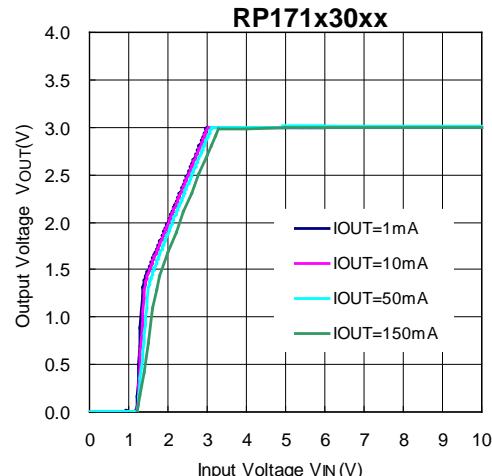
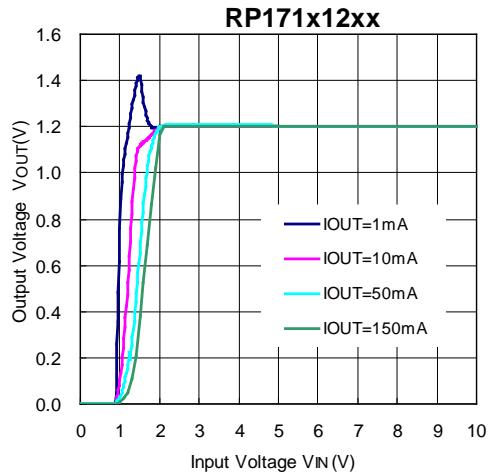
TYPICAL CHARACTERISTICS

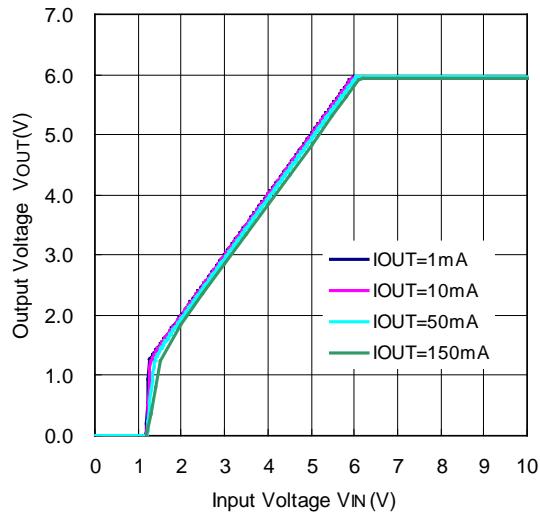
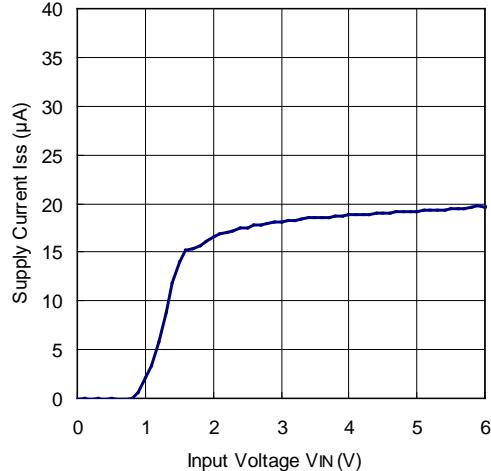
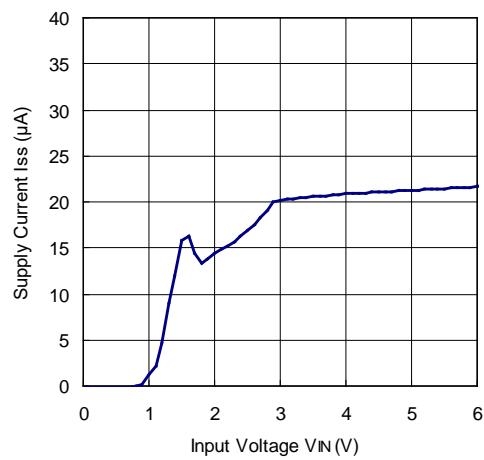
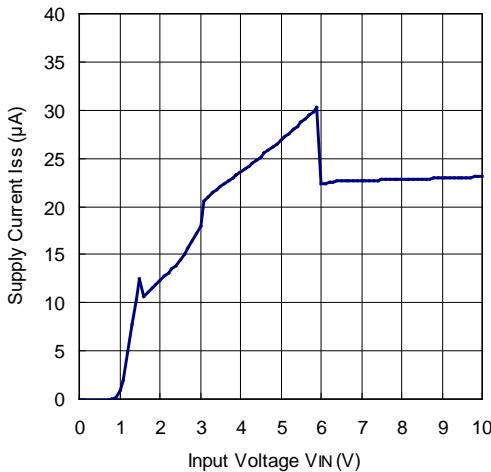
Note: Typical Characteristics are intended to be used as reference data; they are not guaranteed.

1) Output voltage vs. Output Current ($T_a = 25^\circ\text{C}$)

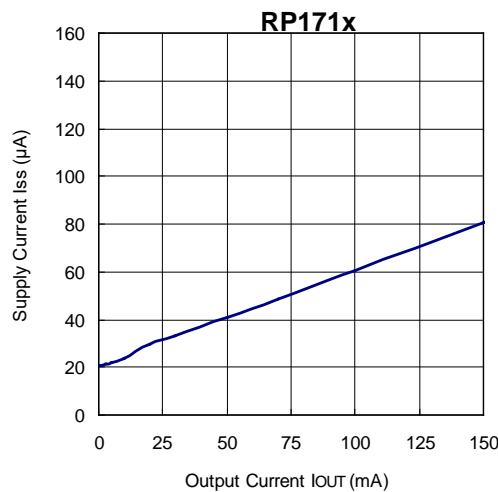


2) Output Voltage vs. Input Voltage ($T_a = 25^\circ\text{C}$)

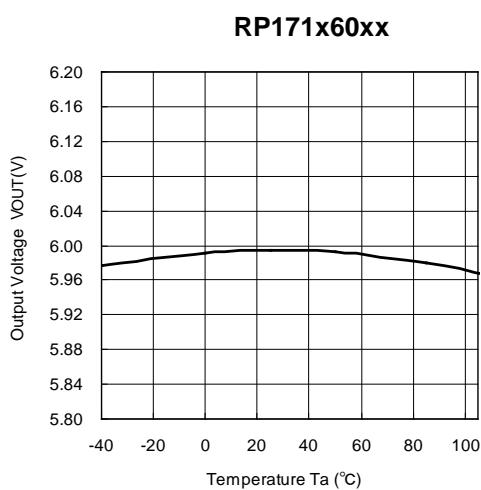
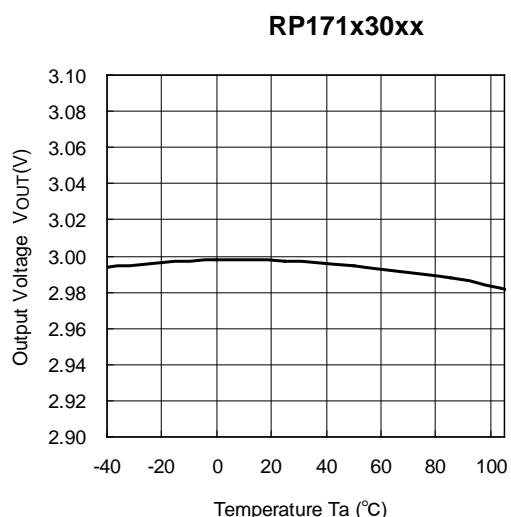
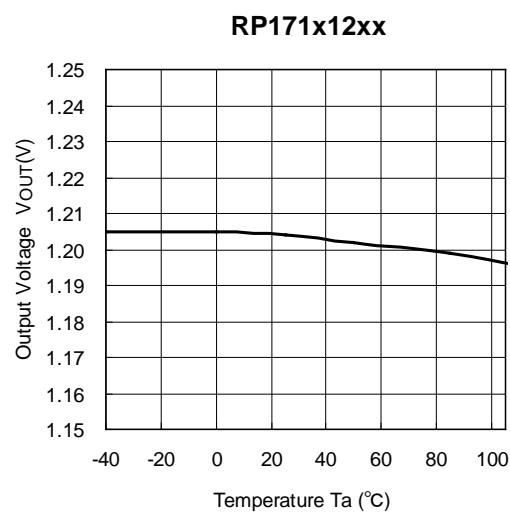


RP171x60xx**3) Supply Current vs. Input Voltage ($T_a = 25^\circ C$)****RP171x12xx****RP171x30xx****RP171x60xx**

4) Supply Current vs. Output Current ($T_a = 25^\circ\text{C}$)



5) Output Voltage vs. Temperature

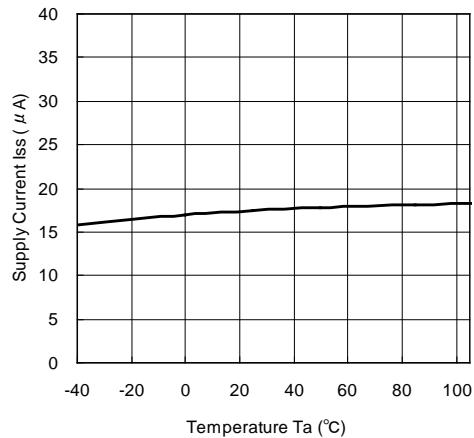


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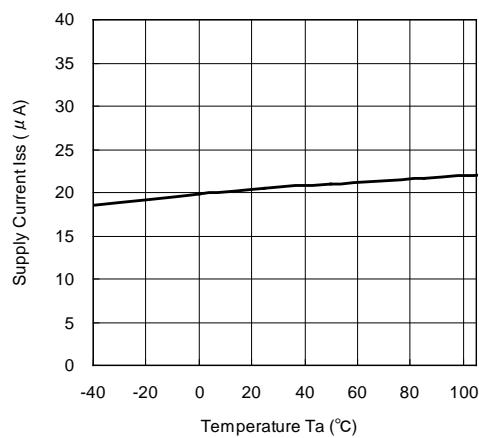
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6) Supply Current vs. Temperature

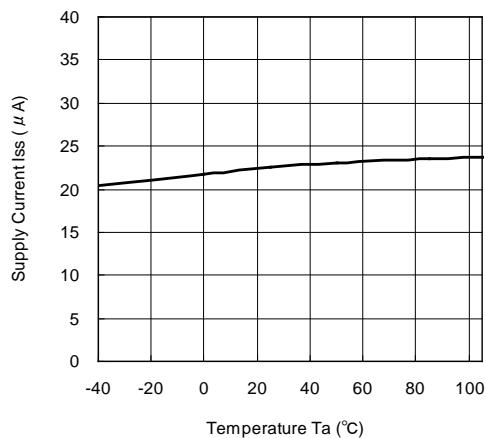
RP171x12xx



RP171x30xx

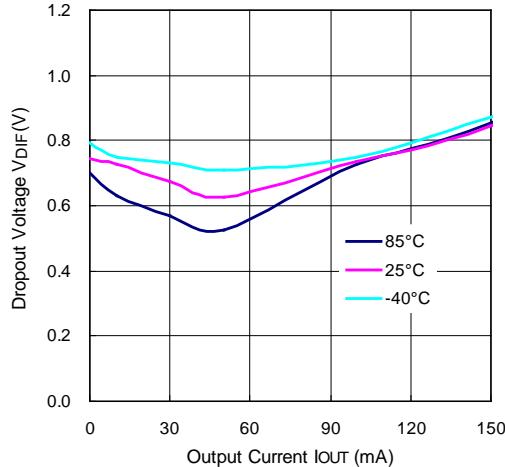


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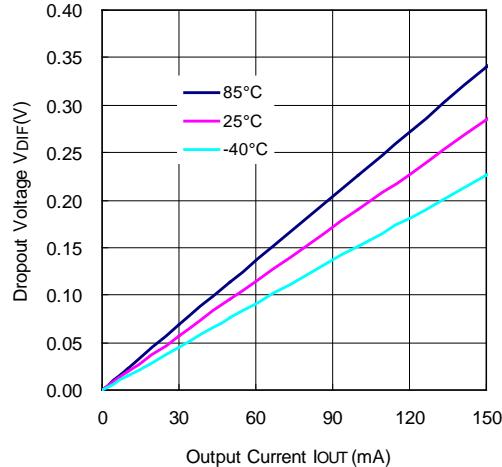


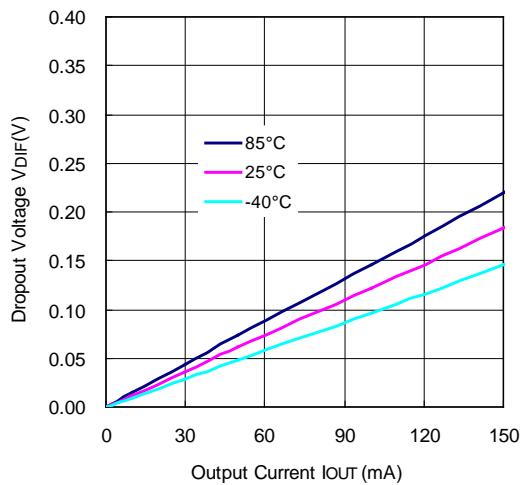
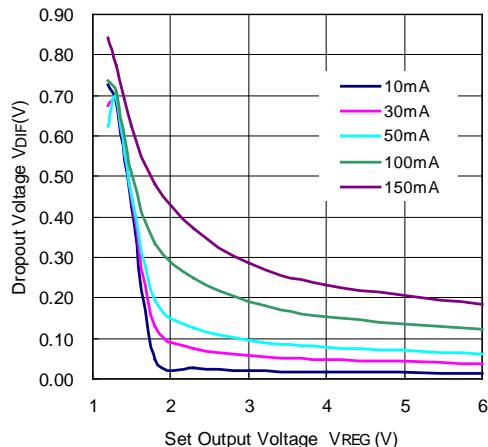
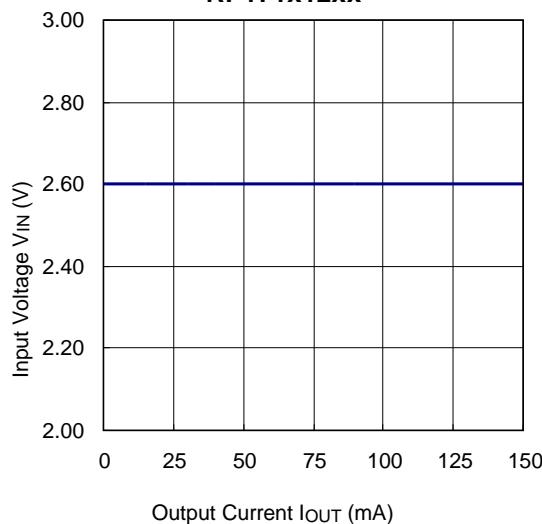
7) Dropout Voltage vs. Output Current

RP171x12xx

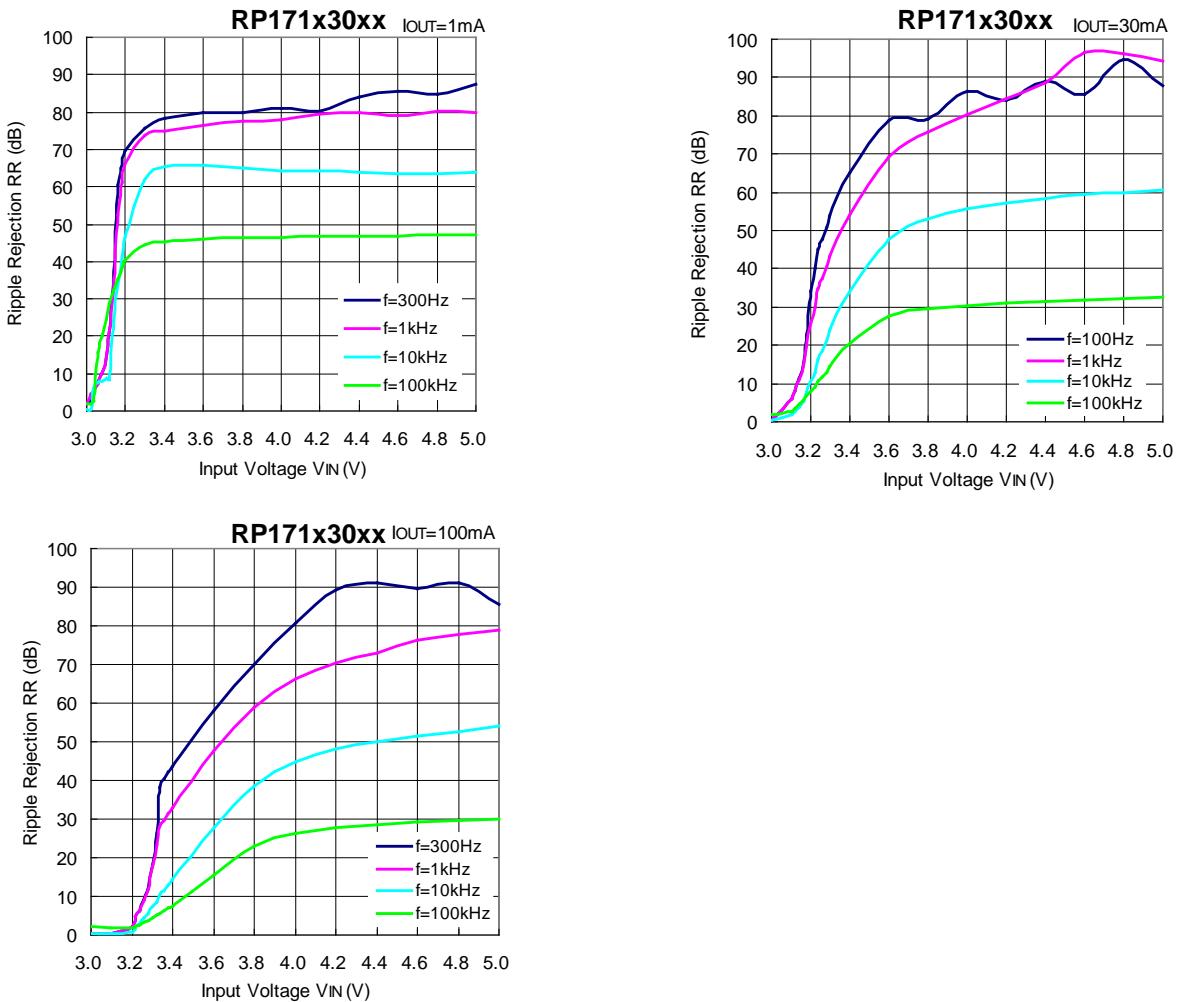
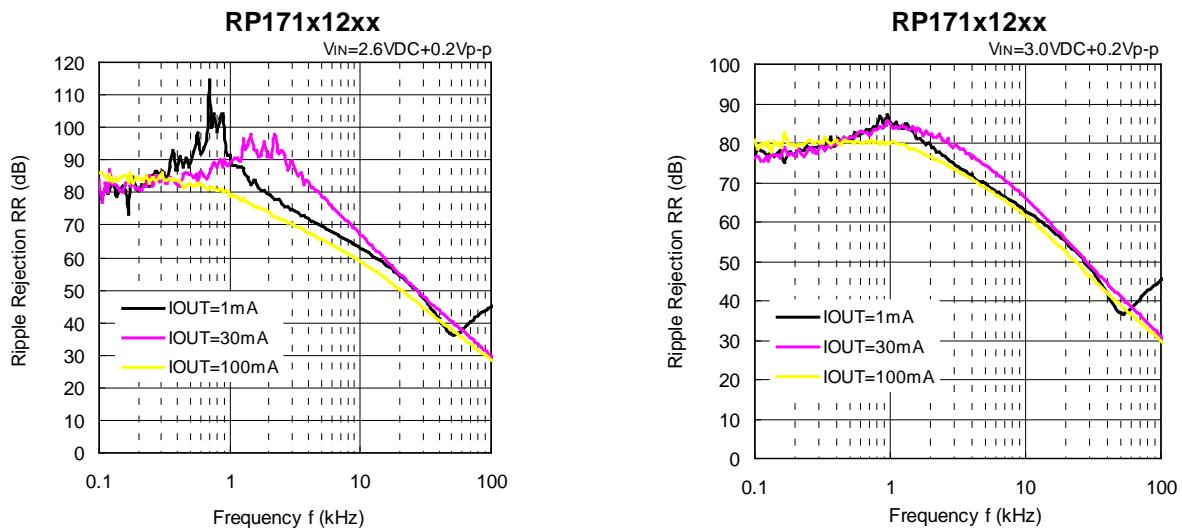


RP171x30xx

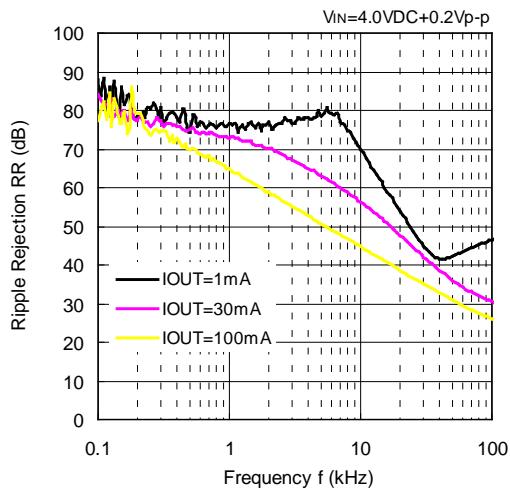


RP171x60xx**8) Dropout Voltage vs. Set Output Voltage ($T_a = 25^{\circ}\text{C}$)****RP171x****9) Minimum Operating Voltage****RP171x12xx**

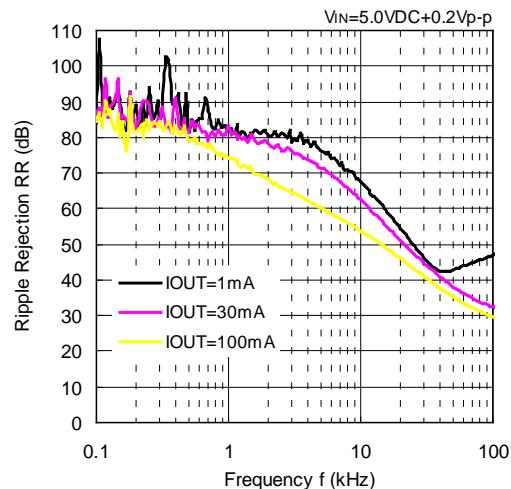
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10) Ripple Rejection vs. Input Bias Voltage (C1 = none, C2 = Ceramic 1.0 μ F, Ripple = 0.2 Vp-p, Ta = 25°C)**11) Ripple Rejection vs. Frequency (C1 = none, C2 = Ceramic 1.0 μ F, Ta = 25°C)**

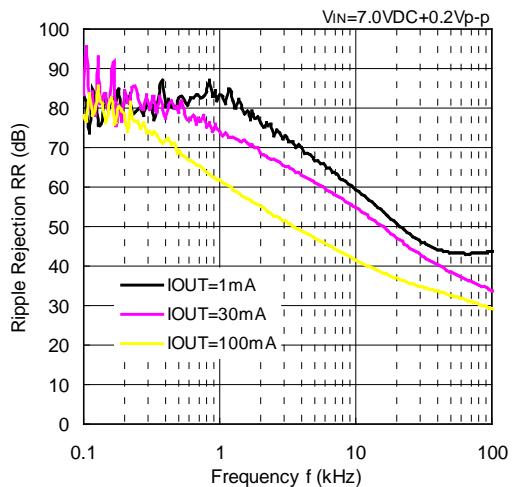
RP171x30xx



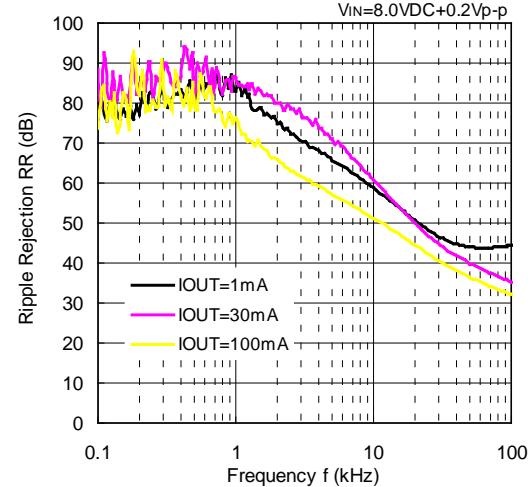
RP171x30xx



RP171x60xx

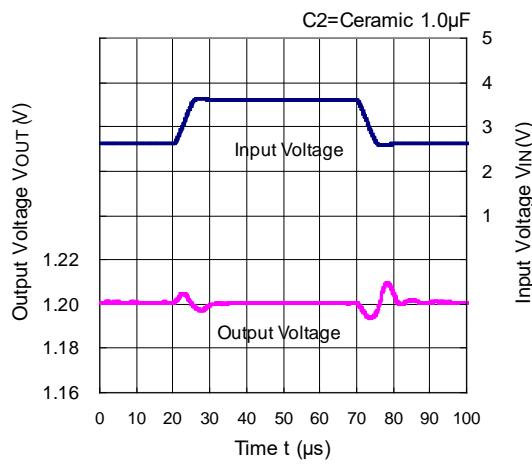


RP171x60xx

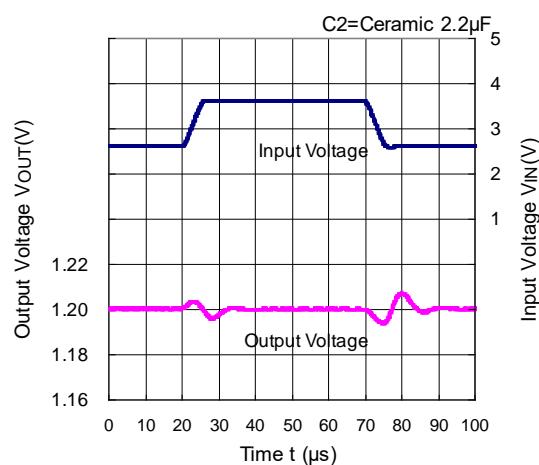


12) Input Transient Response ($C_1 = \text{none}$, $I_{OUT} = 30 \text{ mA}$, $\text{tr} = \text{tf} = 5\mu\text{s}$, $T_a = 25^\circ\text{C}$)

RP171x12xx



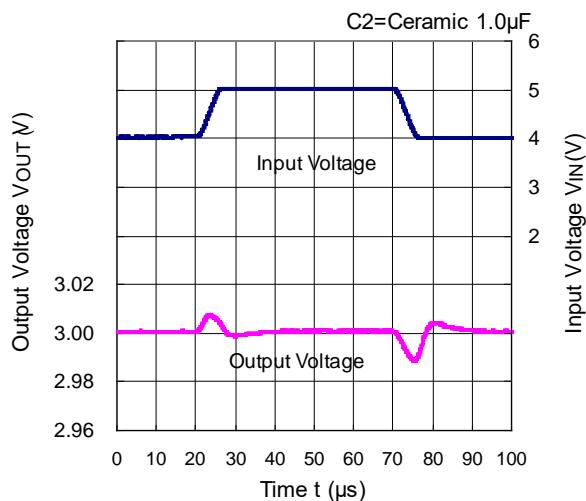
RP171x12xx



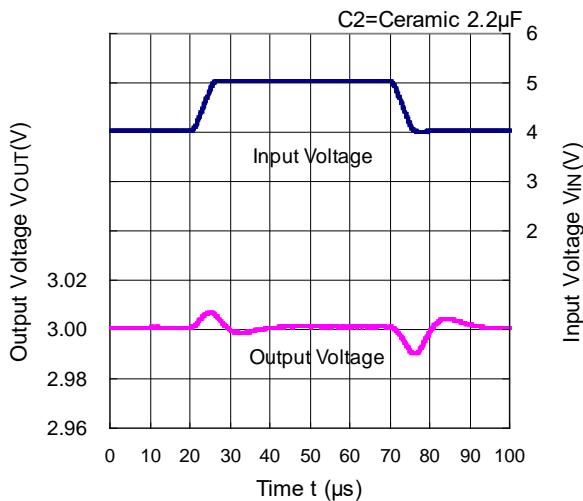
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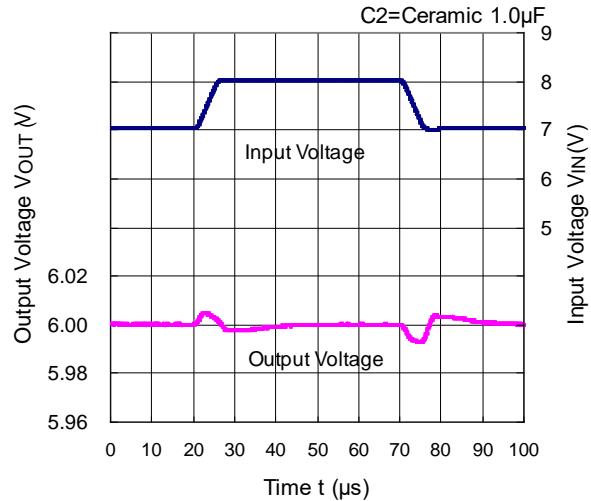
RP171x30xx



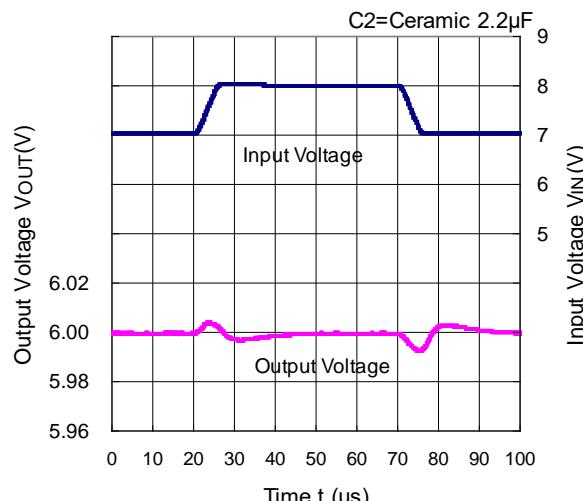
RP171x30xx



RP171x60xx

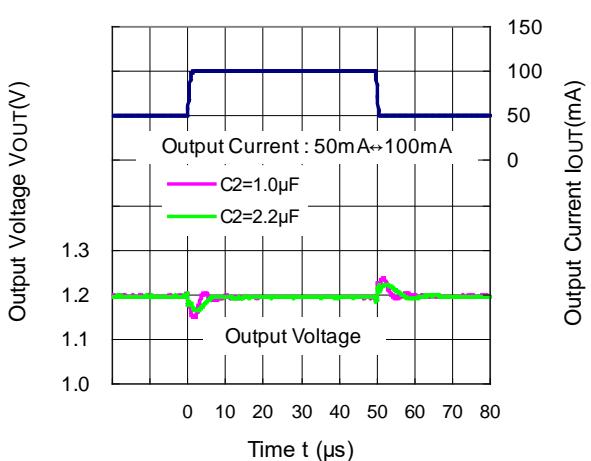


RP171x60xx

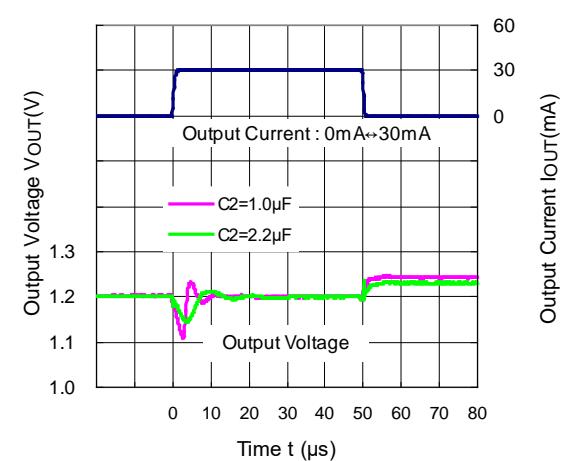


13) Load Transient Response (C1 = Ceramic 1.0 μ F, tr = tf = 500 ns, Ta = 25°C)

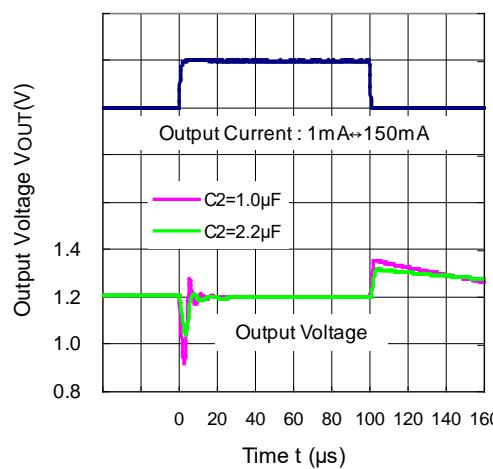
RP171x12xx



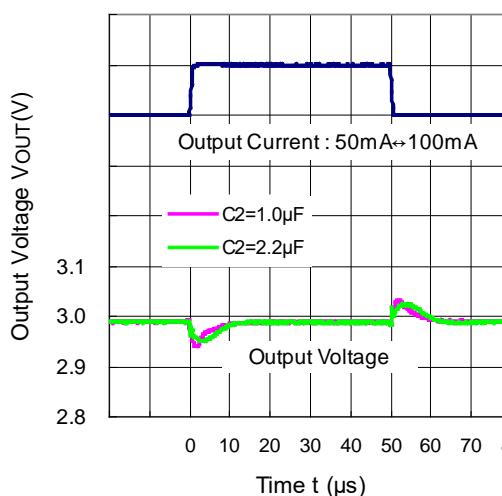
RP171x12xx



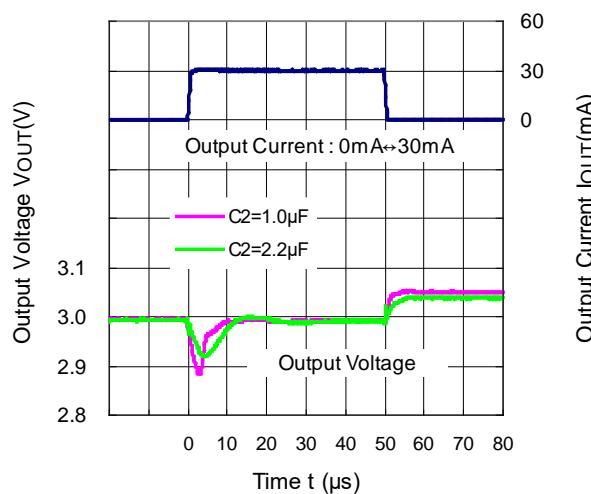
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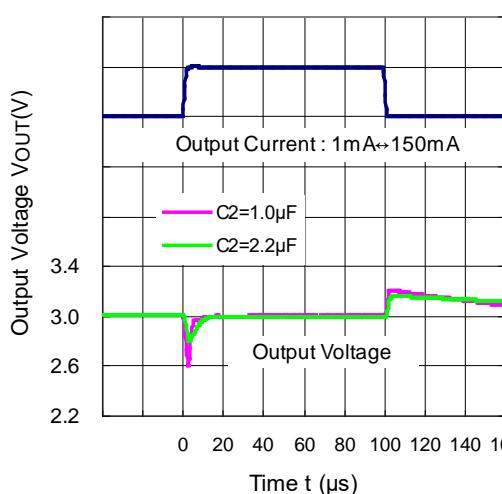
RP171x30xx



RP171x30xx



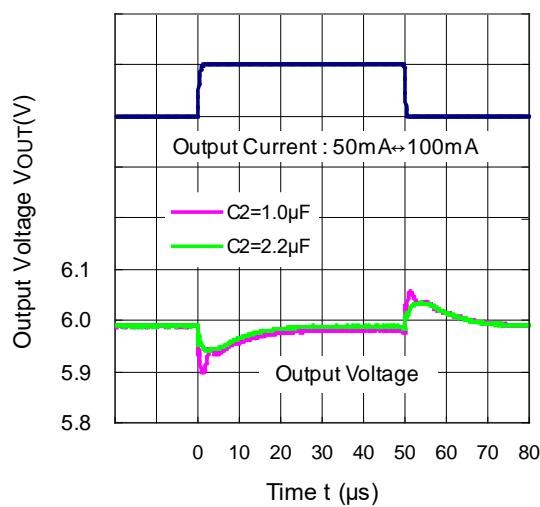
RP171x30xx



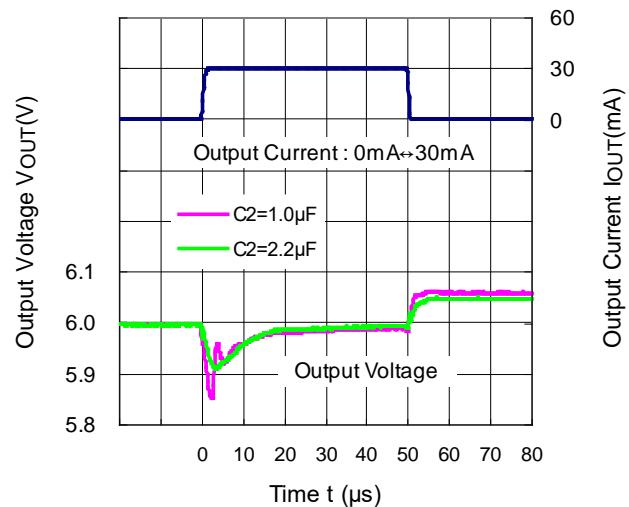
RP171N-Y

No. EA-342-200219

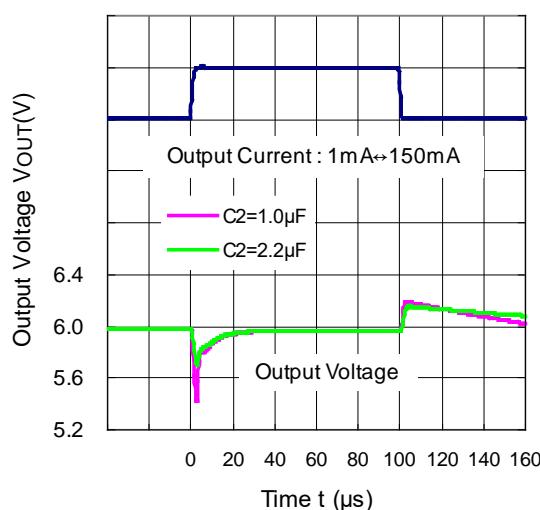
RP171x60xx



RP171x60xx

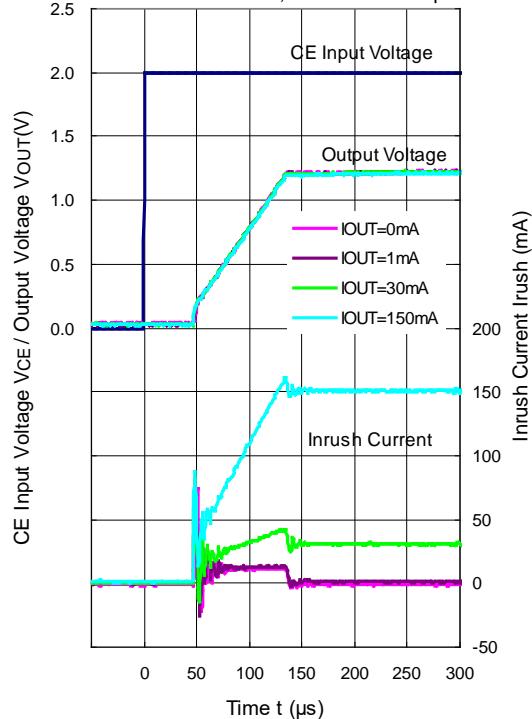


RP171x60xx

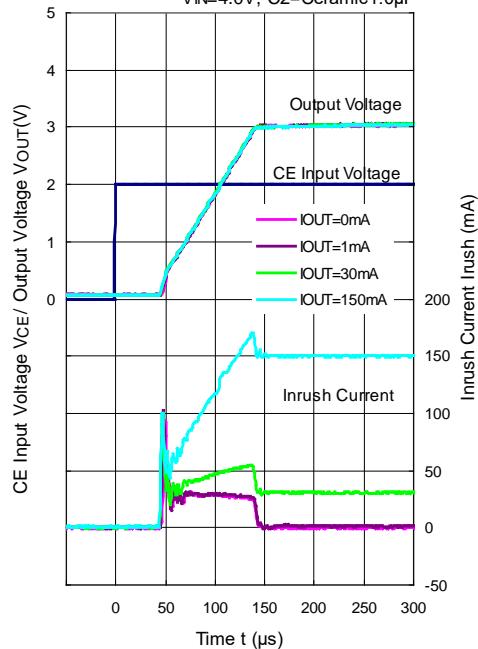


14) Turn On Speed with CE pin (C1 = Ceramic 1.0 μ F, Ta = 25°C)

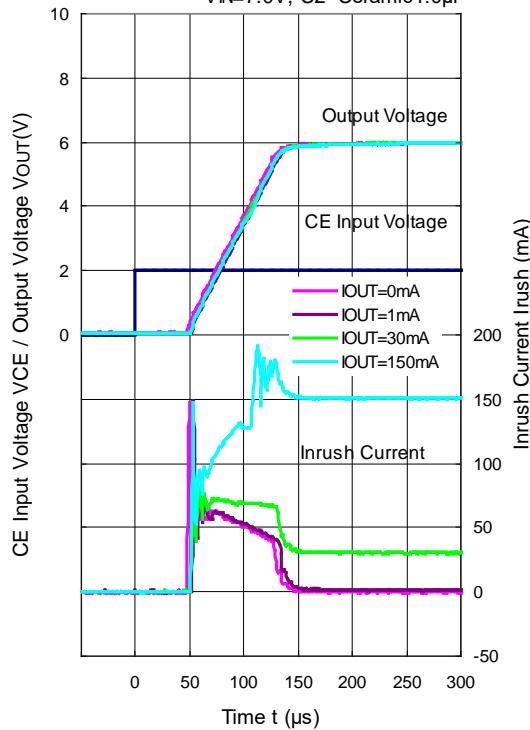
RP171x12xx

VIN=2.6V, C2=Ceramic1.0 μ F

RP171x30xx

VIN=4.0V, C2=Ceramic1.0 μ F

RP171x60xx

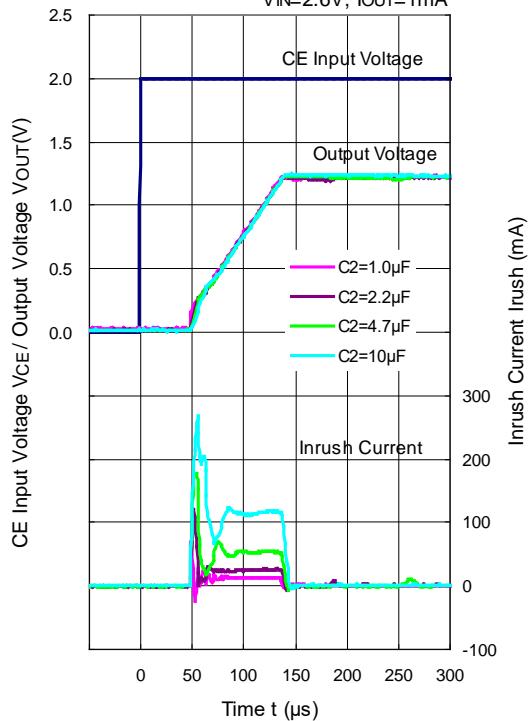
VIN=7.0V, C2=Ceramic1.0 μ F

RP171N-Y

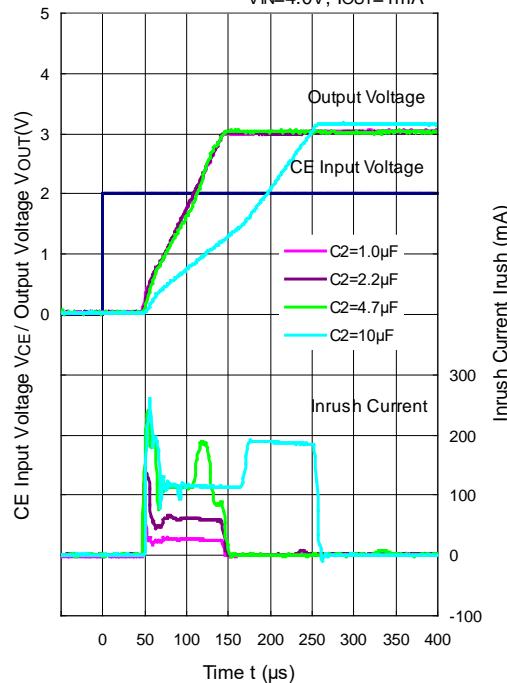
No. EA-342-200219

RP171x12xx

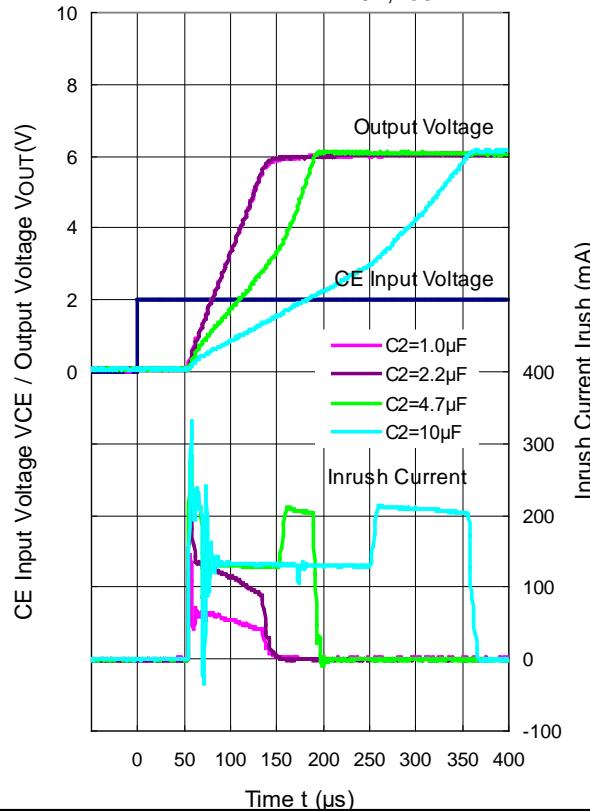
VIN=2.6V, IOUT=1mA

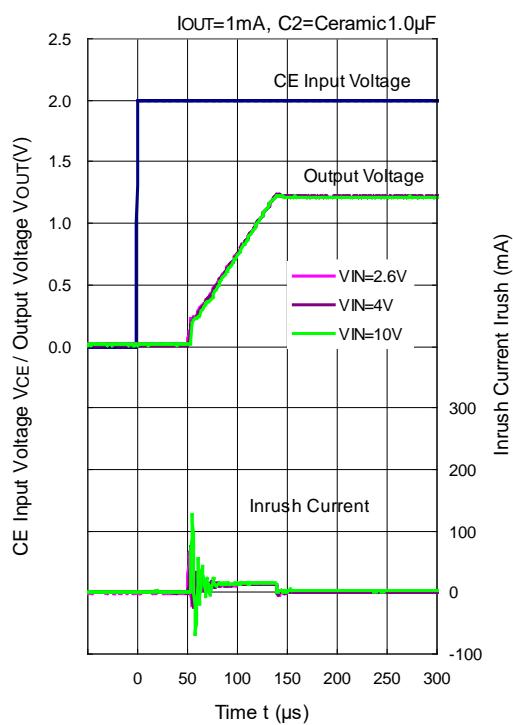
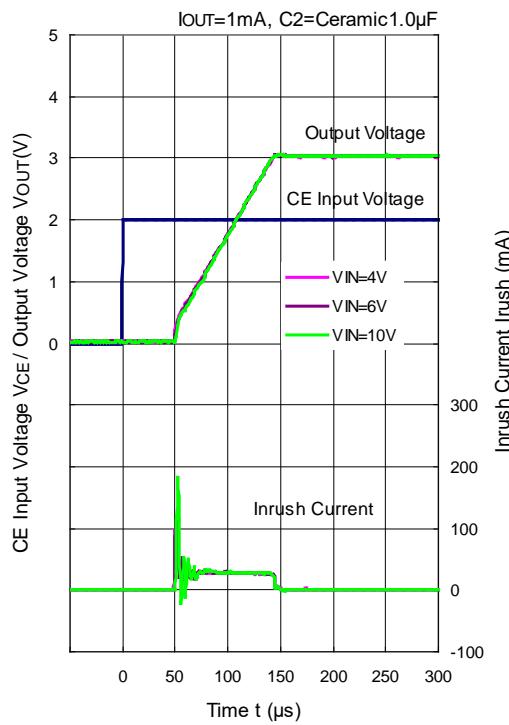
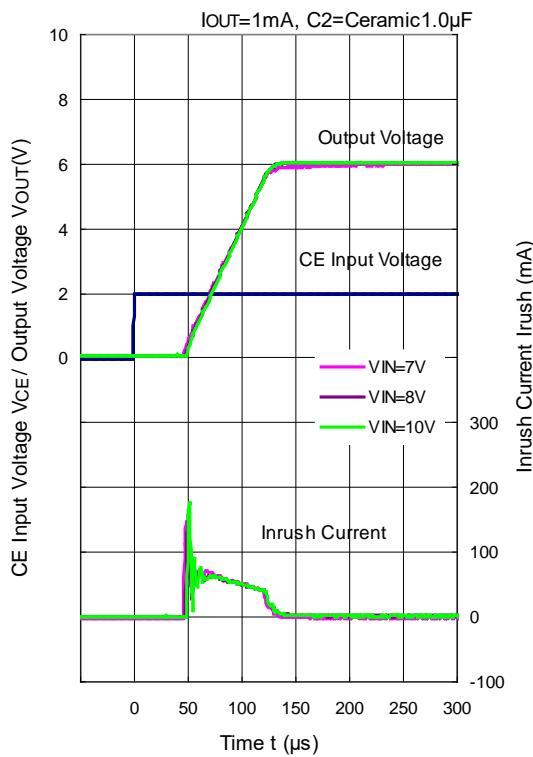
**RP171x30xx**

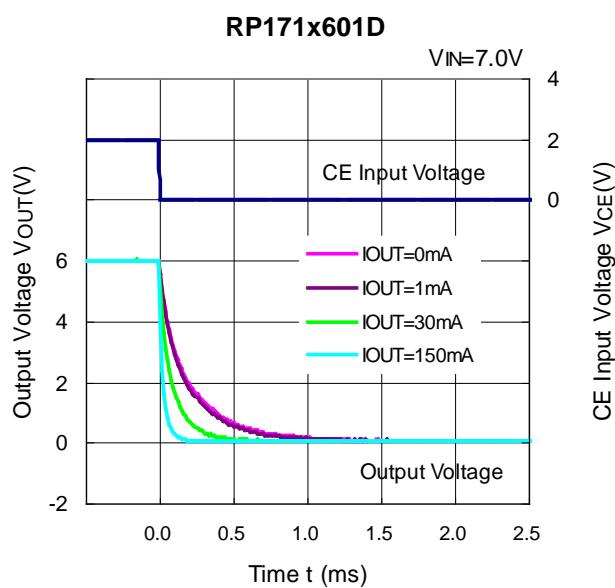
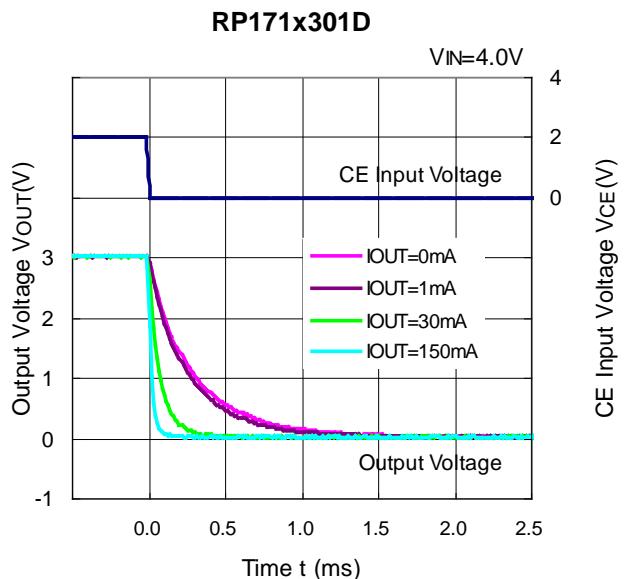
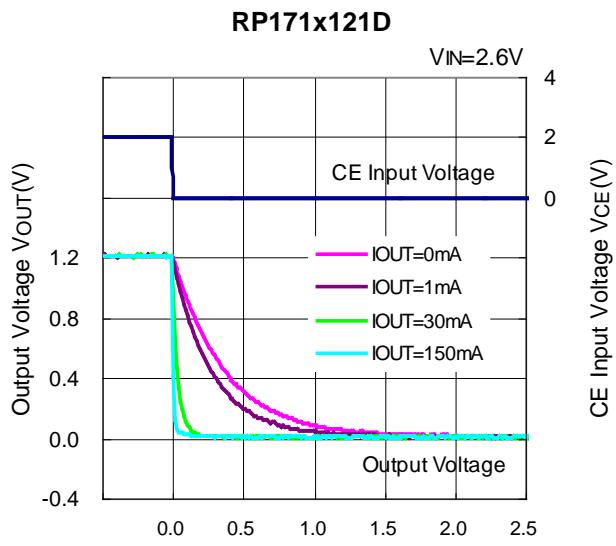
VIN=4.0V, IOUT=1mA

**RP171x60xx**

VIN=7.0V, IOUT=1mA



RP171x12xx**RP171x30xx****RP171x60xx**

15) Turn Off Speed with CE pin (RP171xxxxD) ($C_1 = C_2 = \text{Ceramic } 1.0 \mu\text{F}$, $T_a = 25^\circ\text{C}$)

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

Measurement Conditions

Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	Ø 0.3 mm × 7 pcs

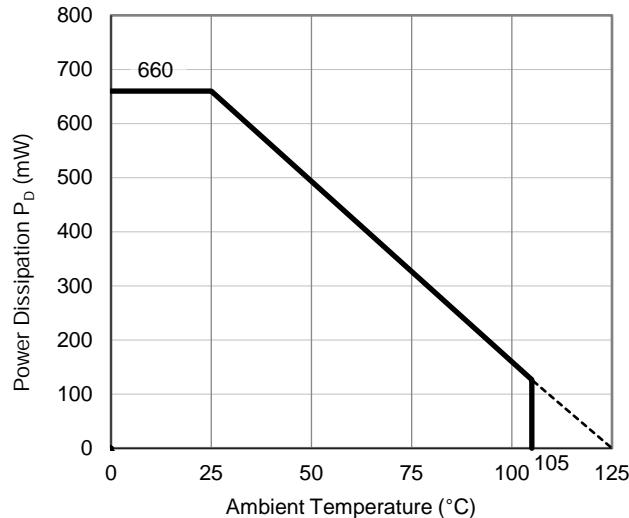
Measurement Result

(Ta = 25°C, Tjmax = 125°C)

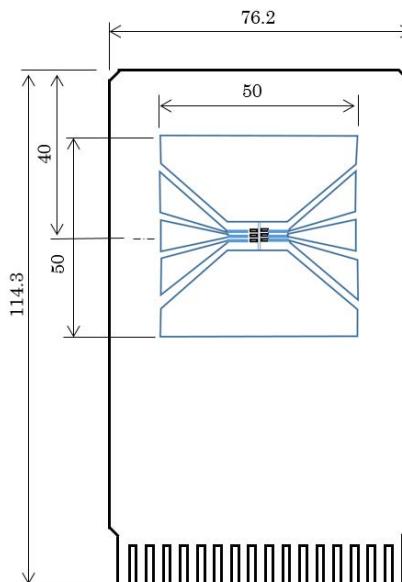
Item	Measurement Result
Power Dissipation	660 mW
Thermal Resistance (θ_{ja})	$\theta_{ja} = 150^\circ\text{C}/\text{W}$
Thermal Characterization Parameter (ψ_{jt})	$\psi_{jt} = 51^\circ\text{C}/\text{W}$

θ_{ja} : Junction-to-Ambient Thermal Resistance

ψ_{jt} : Junction-to-Top Thermal Characterization Parameter



Power Dissipation vs. Ambient Temperature

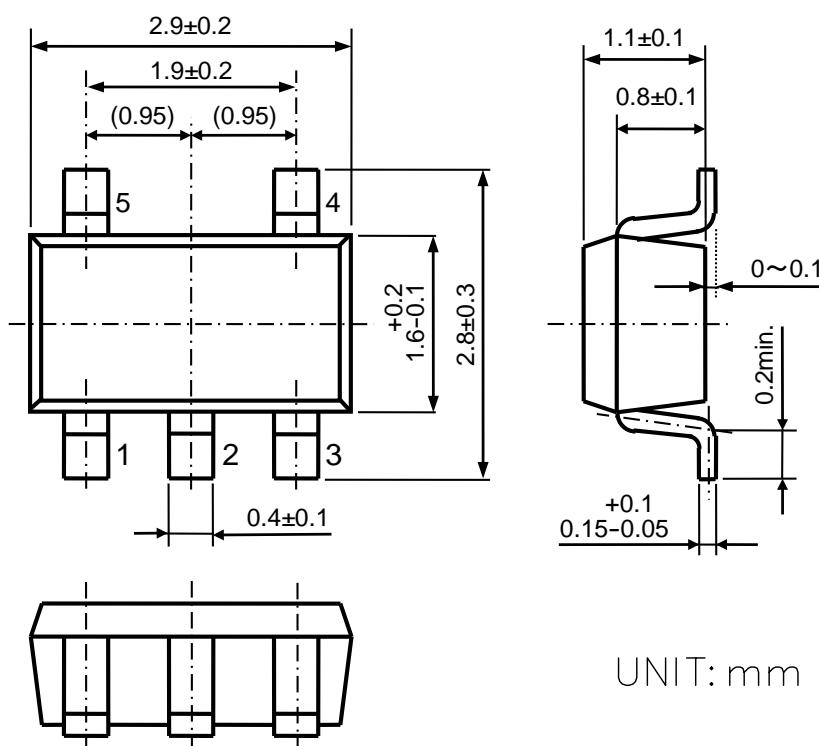


Measurement Board Pattern

PACKAGE DIMENSIONS

SOT-23-5

Ver. A



SOT-23-5 Package Dimensions



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